Metal Oxide Varistor Disk type

Ordering code:

SIOV- S25K320E4R12 Preliminary

SIOV nomenclature

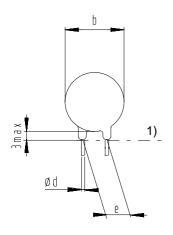
S = Disk type

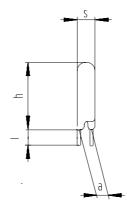
= Rated disk diameter

K = Tolerance of V_V at $1mA : \pm 10\%$

320 = Max. AC voltage E4 = High-Energy series R12 = Customized lead spacing

<u>Figure:</u> Dimensions given in Millimeters (mm)





 $\begin{array}{lllll} b_{max} & = & 27,5 \\ h_{max} & = & 31,0 \\ s_{max} & = & 6,3 \\ e & = & 12,7 \pm 1,0 \end{array}$

 $a = 3,0 \pm 1,0$ $l_{min} = 10,0$ $\emptyset d = 1,0 \pm 0,05$

1) seating plane in accordance with IEC 60717

Electrical data:

Maximum Ratings (85°C):

Max. operating AC voltage 320V V_{RMS} Max. operating DC voltage V_{DC} 420V Surge current (8/20µs) 1 time I_{max} 20000A =Energy absorption (2ms) 1 time W_{max} = 700J Average power dissipation P_{max} 1,0W =

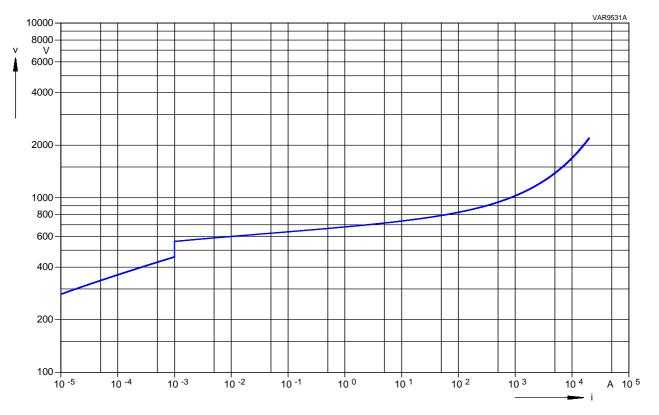
Characteristics (25°C):

Varistor voltage at 1mA $V_V = 510V \pm 10\%$

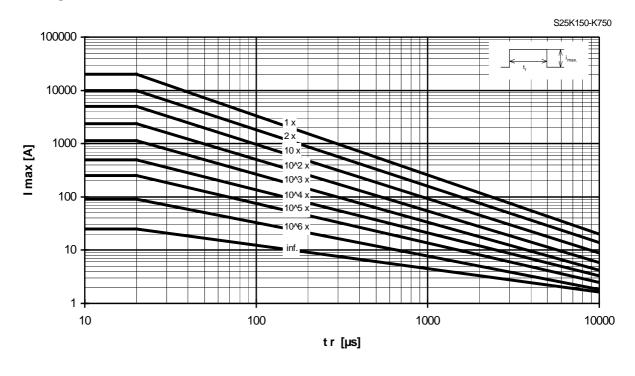
Clamping voltage at 150A (8/20 μ s) $V_{C,max} = 840V$ Typ. capacitance at 1 kHz C = 1150pF

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V/I Characteristic:



Derating:



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Reliability Data:

	Characteristics	Test Methods/Description	Specifications
E	Varistor Voltage	The voltage between two terminals with the specified measuring current applied is called V_v (1 mA _{DC} @ 0.2 - 2 s).	To meet the specified value.
L	Clamping Voltage	The maximum voltage between two terminals with the specified standard impulse current (8/20µs) illustrated below applied.	To meet the specified value.
С		100 90 Leading Edge Trailing Edge	
Т		10 0 0.	
R		Ty. Risk Time ye. Ti. Doney tome to half value ye. Or. Nominal start In. Peak value	
I			
С	Surge current derating, 8/20 µs	100 surge currents (8/20 µs), unipolar, interval 30 s, amplitude corresponding to derating curve for 20 µs	Δ V/V (1 mA) ≤ 10 % (measured in direction of surge
А	0/20 μ3	101 20 μ3	current) No visible damage
L	Surge current derating, 2 ms	100 surge currents (2ms), unipolar, interval 120s, amplitude corresponding to derating curve for 2ms	Δ V/V (1 mA) ≤ 10 % (measured in direction of surge current) No visible damage

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	Characteristics	Test Methods/Description	Specifications
	Tensile strength	After gradually applying the force specified below and keeping the unit fixed for 10 seconds, the terminal shall be visually examined for any damage.	Δ V/V (1 mA) ≤ 5 % No break of solder joint, no wire break
М		Terminal diameter Force 0.5 mm 5 N 0.6 mm 10 N 0.8 mm 10 N 1.0 mm 20 N	
E C	Vibration	After repeatedly applying a single harmonic vibration according to the table below. Thereafter, the unit shall be visually examined.	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage
Н		frequency range: 10 55 Hz amplitude: 0.75 mm or 98 m/s² duration: 6 h (3 x 2 h) pulse: sine wave	
A N	Solderability	After dipping the terminals to a depth of approximately 3 mm from the body in a soldering bath of 235°C for 5 seconds, the terminals shall be visually examined.	The inspection shall be carried out under adequate light with normal eyesight or with the assistance
С			of a magnifier capable of giving a magnification of 4 times to 10 times. The dipped surface shall be covered
А			with a smooth and bright solder coating with no more than
L			small amounts of scattered imperfections such as pinholes or unwetted or de-wetted areas. These imperfections shall not be concentrated in one area.

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	Characteristics	Test Methods/Description	Specifications
М	Resistance to	Each lead shall be dipped into a solder bath	\(\Delta \text{V/V} \) (1 mA)
Е	soldering heat	having a temperature of $260 \pm 5^{\circ}$ C to a point 2.0 to 2.5 mm from the body of the unit, be held	≤ 5 % No visible damage
С		there for 10 ± 1 s and then be stored at room	
Н		temperature and normal humidity for 1 to 2 hours. The change of V _v and mechanical	
Α		damages shall be examined.	
Ν	Electric strength	2500 V _{RMS} , 10 s	No breakdown
I		The varistor is placed in a container holding 1.6 \pm 0.2 mm diameter metal balls such that only the	
С		terminations of the varistor are protruding.	
Α		The specified voltage shall be applied between both terminals of the specimen connected	
L		together and the electrode inserted between the metal balls.	

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	Characteristics	Test Methods/Description	Specifications
E N	Max. AC operating voltage	After being continuously applied the maximum allowable voltage at $85 \pm 2^{\circ}\text{C}$ for 1000 hours, the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_v shall be measured.	Δ V/V (1 mA) ≤ 10 %
V	Damp heat, steady state	The specimen shall be subjected to $40 \pm 2^{\circ}\text{C}$, 90 to 95 % r.H. for 56 days without load and then stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_{ν} shall be measured.	Δ V/V (1 mA) ≤ 10 %
R	Climatic sequence	The specimen shall be subjected to: a) dry heat at +85°C, 16 h	$ \Delta \text{ V/V (1 mA)} $ $\leq 10 \%$
0		 b) damp heat, 1st cycle: 55°C, 93 % r.H., 24 h c) cold, -40°C, 2 h d) damp heat, additional 5 cycles: 55°C, 93 % r.H., 24 h/cycle 	
N M		Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V _v shall be measured.	
E	Fast temperature cycling	The temperature cycle shown below shall be repeated 5 times. Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. The change of V _v and	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage
N		mechanical damage shall be examined.	
Т		Step Temperature (°C) Period (min.) 1 -40 \pm 3 30 \pm 3 2 transition time < 10 s 3 85 \pm 2 30 \pm 3	
А			
L			

Note: More details can be found in the data book 'SIOV Metal Oxide Varistors', Ordering No.

EPC: 62002-7600

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